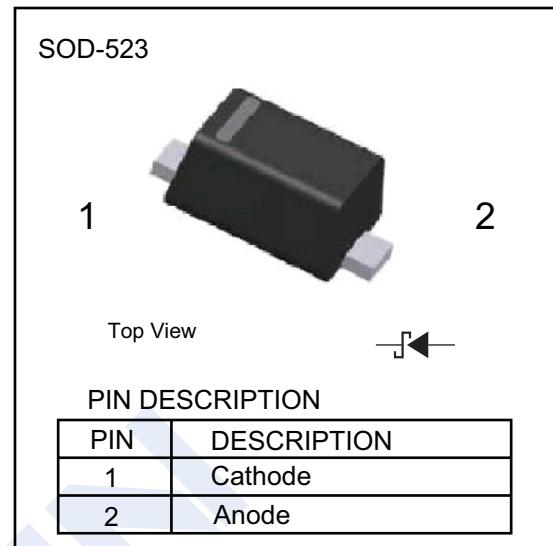


**Schottky Diodes****BAT41KF1LM****■ Features**

- Low leakage current losses
- Negligible switching losses
- Low forward and reverse recovery times
- Extremely fast switching
- Surface mount device
- Low capacitance diode

**■ Absolute Maximum Ratings( $T_j = 25^\circ C$ , unless otherwise specified)**

Parameter	Symbol	Rating	Unit
Repetitive Peak Reverse Voltage	V <sub>R</sub> RM	100	V
Continuous Forward Current	I <sub>F</sub>	200	mA
Surge Non-repetitive Forward Current $t_p=10\text{ms}$ Sinusoidal	I <sub>FSM</sub>	1	A
Thermal Resistance Junction to Ambient (Note1)	R <sub>JA</sub>	600	°C/W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature range	T <sub>stg</sub>	-55 to 150	

Note1: Epoxy printed circuit board with recommended pad layout

**■ Electrical Characteristics**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse breakdown voltage	V <sub>R</sub>	I <sub>R</sub> = 100 μA	100			V
Forward voltage <sup>(1)</sup>	V <sub>F1</sub>	I <sub>F</sub> = 1 mA, T <sub>j</sub> = 25°C			0.45	
	V <sub>F2</sub>	I <sub>F</sub> = 200 mA, T <sub>j</sub> = 25°C			1	
Reverse voltage leakage current <sup>(2)</sup>	I <sub>R1</sub>	V <sub>R</sub> =50 V, T <sub>j</sub> = 25°C			0.1	μA
	I <sub>R2</sub>	V <sub>R</sub> =50 V, T <sub>j</sub> = 100°C			20	
Capacitance between terminals	C <sub>T</sub>	V <sub>R</sub> = 1 V, F = 1 MHz		3	10	pF

Notes:

1. Pulse test:  $t_p=380 \mu\text{s}, \delta<2\%$
2. Pulse test:  $t_p=5 \text{ ms}, \delta<2\%$

**■ Marking**

Marking	41
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## Schottky Diodes

### BAT41KF1LM

#### ■ Typical Characteristics

Figure 1. Average forward power dissipation versus average forward current

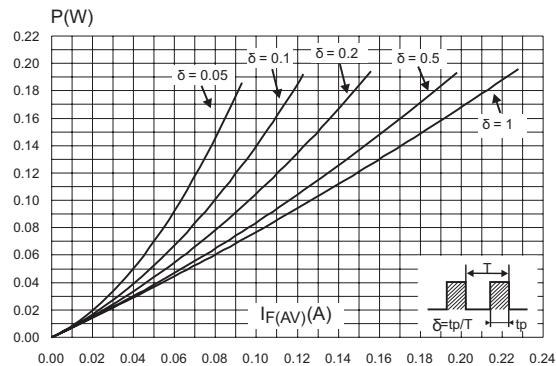


Figure 2. Average forward current versus ambient temperature ( $\delta = 1$ )

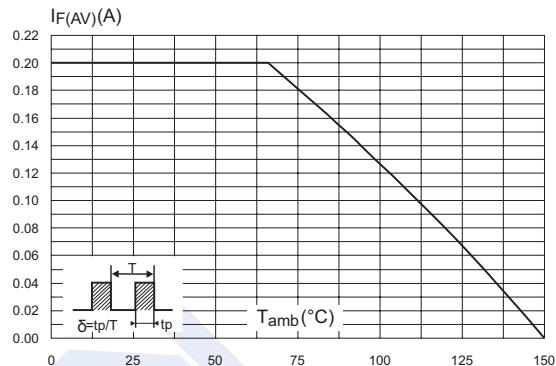


Figure 3. Reverse leakage current versus reverse applied voltage (typical values)

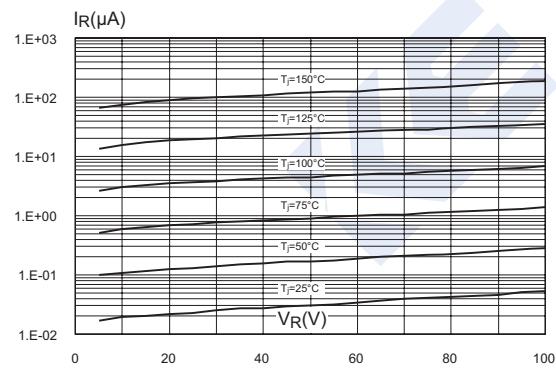
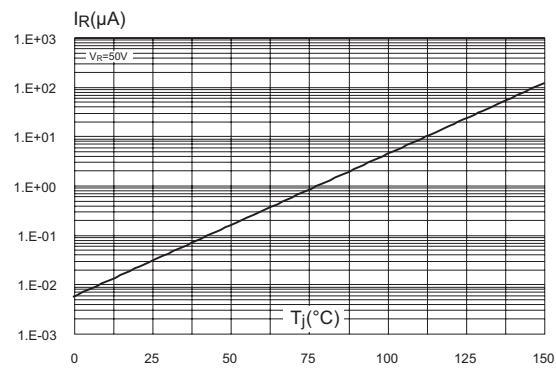


Figure 4. Reverse leakage current versus junction temperature (typical values)



## Schottky Diodes

### BAT41KF1LM

#### ■ Typical Characteristics

Figure 5. Junction capacitance versus reverse applied voltage (typical values)

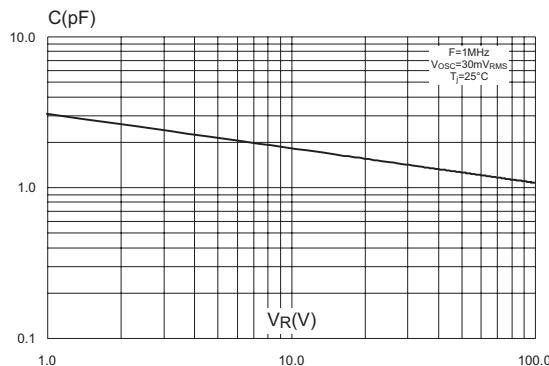


Figure 6. Forward voltage drop versus forward current (typical values)

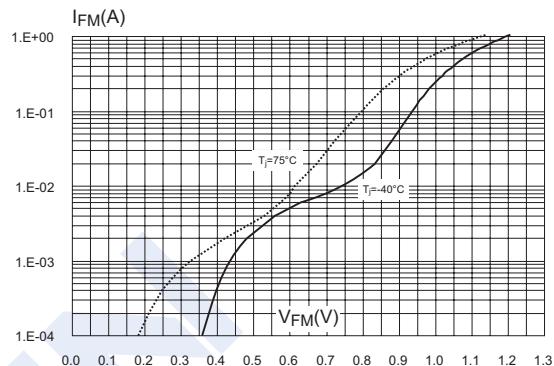


Figure 7. Forward voltage drop versus forward current (typical values)

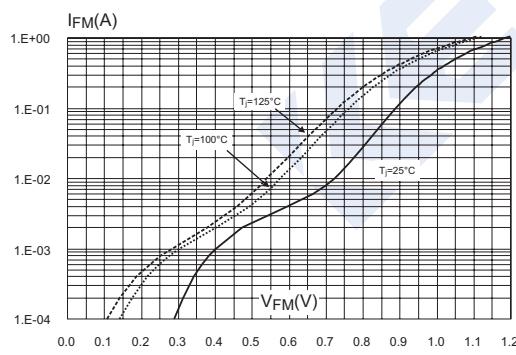
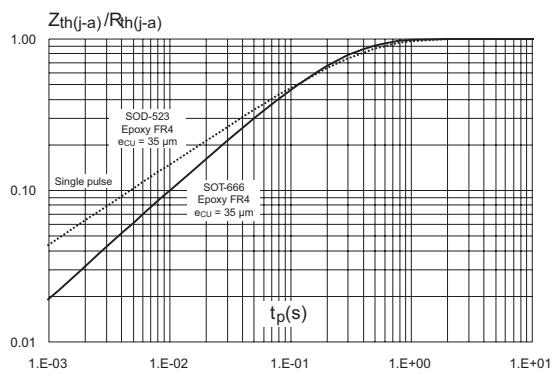
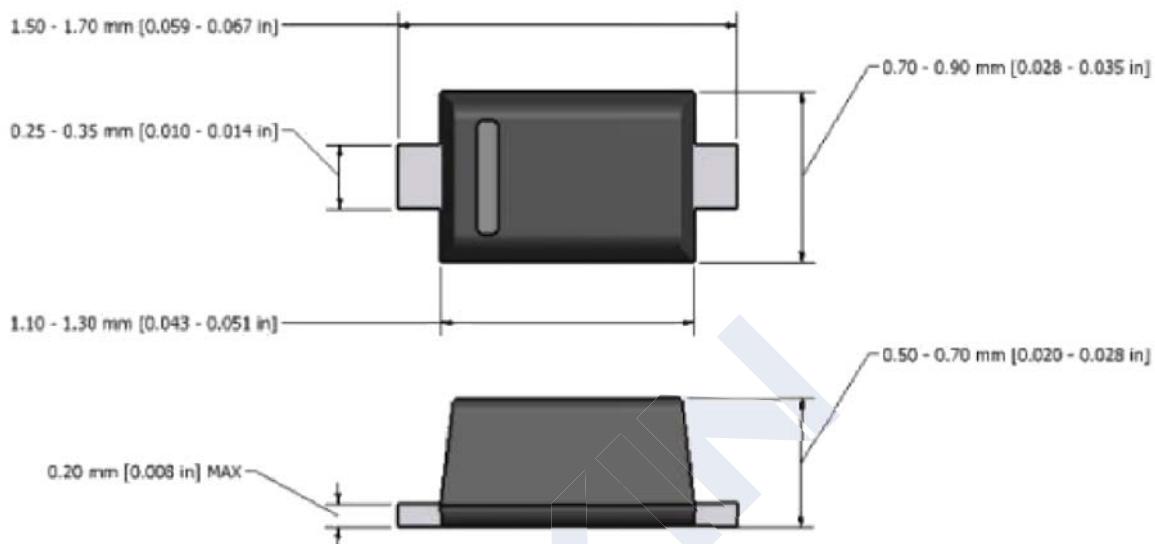


Figure 8. Relative variation of thermal impedance junction to ambient versus pulse duration (printed circuit board, epoxy FR4,  $e_{CU}=35\mu m$ )



**Schottky Diodes****BAT41KF1LM****■ Package Outline Dimensions (SOD-523)**

**Note:** Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.

**■ The Recommended Mounting Pad Size**